

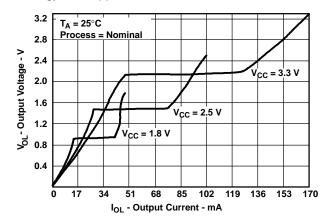
FEATURES

- Member of the Texas Instruments Widebus™
 Family
- EPIC[™] (Enhanced-Performance Implanted CMOS) Submicron Process
- DOC™ (Dynamic Output Control) Circuit Dynamically Changes Output Impedance, Resulting in Noise Reduction Without Speed Degradation
- Less Than 2-ns Maximum Propagation Delay at 2.5-V and 3.3-V V_{CC}
- Dynamic Drive Capability Is Equivalent to Standard Outputs With I $_{\rm OH}$ and I $_{\rm OL}$ of \pm 24 mA at 2.5-V V $_{\rm CC}$

- Overvoltage-Tolerant Inputs/Outputs Allow Mixed-Voltage-Mode Data Communications
- I_{off} Supports Partial-Power-Down Mode Operation
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
- Latch-Up Performance Exceeds 250 mA Per JESD 78
- Package Options Include Plastic Thin Shrink Small-Outline (DGG) and Thin Very Small-Outline (DGV) Packages

DESCRIPTION

A Dynamic Output Control (DOCTM) circuit is implemented, which, during the transition, initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figure 1 shows typical V_{OL} vs I_{OL} and V_{OH} vs I_{OH} curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DOC circuit provides a maximum dynamic drive that is equivalent to a high-drive standard-output device. For more information, refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number SCEA006, and *Dynamic Output Control (DOCTM) Circuitry Technology and Applications*, literature number SCEA009.



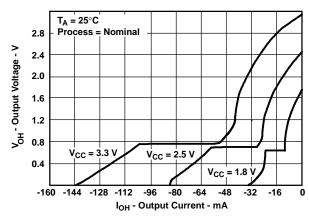


Figure 1. Output Voltage vs Output Current

This 16-bit (dual octal) noninverting bus transceiver is operational at 1.2-V to 3.6-V V_{CC} , but is designed specifically for 1.65-V to 3.6-V V_{CC} operation.

The SN74AVC16245 is designed for asynchronous communication between data buses. The control-function implementation minimizes external timing requirements.

This device can be used as two 8-bit transceivers or one 16-bit transceiver. It allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.



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DESCRIPTION (CONTINUED)

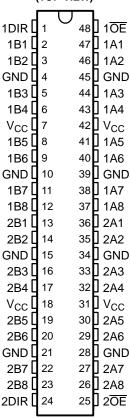
To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The SN74AVC16245 is characterized for operation from -40°C to 85°C.

TERMINAL ASSIGNMENTS

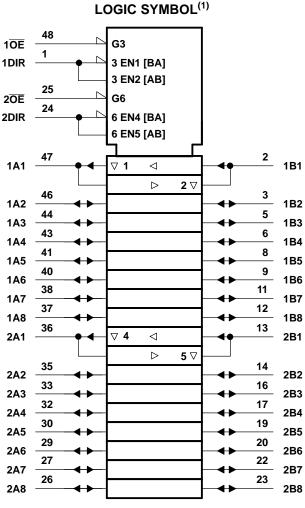
DGG OR DGV PACKAGE (TOP VIEW)



FUNCTION TABLE (EACH 8-BIT TRANSCEIVER)

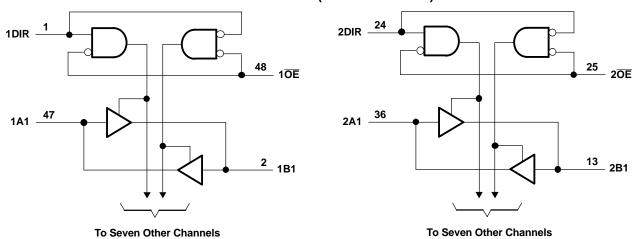
INP	UTS	OPERATION
ŌΕ	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	Χ	Isolation





(1) This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

LOGIC DIAGRAM (POSITIVE LOGIC)



SN74AVC16245 **16-BIT BUS TRANSCEIVER** WITH 3-STATE OUTPUTS

SCES142L-JULY 1998-REVISED MAY 2005



Absolute Maximum Ratings(1)

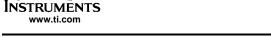
over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range	-0.5	4.6	V	
V_{I}	Input voltage range ⁽²⁾		-0.5	4.6	V
V _O	Voltage range applied to any input/output when the output is in the high-impedance or p	power-off state ⁽²⁾	-0.5	4.6	V
Vo	Voltage range applied to any input/output who	en the output is in the high or low state (2)(3)	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through each V _{CC} or GNE)		±100	mA
0	Declare thermal impedance (4)	DGG package		70	°C ///
θ_{JA}	Package thermal impedance (4)	DGV package		58	°C/W
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.

The package thermal impedance is calculated in accordance with JESD 51.



16-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

SCES142L-JULY 1998-REVISED MAY 2005

Recommended Operating Conditions(1)

			MIN	MAX	UNIT
V	Supply voltage	Operating	1.4	3.6	V
V_{CC}	Supply voltage	Data retention only	1.2		V
		V _{CC} = 1.2 V	V _{CC}		
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	0.65 × V _{CC}		
V_{IH}	High-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	0.65 × V _{CC}		V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2		
		V _{CC} = 1.2 V		GND	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		$0.35 \times V_{CC}$	
V_{IL}	Low-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	
		V _{CC} = 3 V to 3.6 V		0.8	
V_{I}	Input voltage		0	3.6	V
V	Output valtage	Active state	0	V_{CC}	V
Vo	Output voltage	3-state	0	3.6	V
		V _{CC} = 1.4 V to 1.6 V		-2	
	Static high-level output current (2)	V _{CC} = 1.65 V to 1.95 V		-4	A
I _{OHS}	Static high-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-8	mA
		V _{CC} = 3 V to 3.6 V		-12	
		V _{CC} = 1.4 V to 1.6 V		2	
I _{OLS}	Static low-level output current ⁽²⁾	V _{CC} = 1.65 V to 1.95 V		4	A
	Static low-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		8	mA
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		12	
Δt/Δν	Input transition rise or fall rate	V _{CC} = 1.4 V to 3.6 V		5	ns/V
T _A	Operating free-air temperature		-40	85	°C

 ⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.
 (2) Dynamic drive capability is equivalent to standard outputs with I_{OH} and I_{OL} of ±24 mA at 2.5-V V_{CC}. See Figure 1 for V_{OL} vs I_{OL} and V_{OH} vs I_{OH} characteristics. Refer to the TI application reports, AVC Logic Family Technology and Applications, literature number SCEA006, and Dynamic Output Control (DOC™) Circuitry Technology and Applications, literature number SCEA009.

SCES142L-JULY 1998-REVISED MAY 2005



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST C	ONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾ M	X UNIT
		$I_{OHS} = -100 \mu A$		1.4 V to 3.6 V	$V_{CC} - 0.2$		
		$I_{OHS} = -2 \text{ mA},$	$V_{IH} = 0.91 \ V$	1.4 V	1.05		
V_{OH}		$I_{OHS} = -4 \text{ mA},$	$V_{IH} = 1.07 V$	1.65 V	1.2		V
		$I_{OHS} = -8 \text{ mA},$	$V_{IH} = 1.7 V$	2.3 V	1.75		
		$I_{OHS} = -12 \text{ mA},$	$V_{IH} = 2 V$	3 V	2.3		
		$I_{OLS} = 100 \mu A$		1.4 V to 3.6 V		(0.2
		$I_{OLS} = 2 \text{ mA},$	$V_{IL} = 0.49 V$	1.4 V		(0.4
V_{OL}		$I_{OLS} = 4 \text{ mA},$	$V_{IL} = 0.57 V$	1.65 V		0.	45 V
		$I_{OLS} = 8 \text{ mA},$	$V_{IL} = 0.7 V$	2.3 V		0.	55
		$I_{OLS} = 12 \text{ mA},$	$V_{IL} = 0.8 V$	3 V		().7
I	Control inputs	$V_I = V_{CC}$ or GND		3.6 V		±ź	2.5 μΑ
I _{off}		V_I or $V_O = 3.6 \text{ V}$		0		±	10 μΑ
$I_{OZ}^{(2)}$		$V_O = V_{CC}$ or GND,	$V_{I}(\overline{OE}) = V_{CC}$	3.6 V		±12	2.5 μΑ
I _{CC}		$V_I = V_{CC}$ or GND,	$I_O = 0$	3.6 V			40 μΑ
<u></u>	Control inputs	V – V or CND		2.5 V		3	pF
C _i	Control inputs	$V_I = V_{CC}$ or GND		3.3 V	·	3	þΓ
C	A or P porto	V - V or CND		2.5 V		9	nE
C _{io}	A or B ports	$V_O = V_{CC}$ or GND		3.3 V		9	pF

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2 through Figure 5)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.2 V	V _{CC} = 1 ± 0.1		V _{CC} = ± 0.1		V _{CC} = . ± 0.2		V _{CC} = ± 0.3		UNIT
	(INFOT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	B or A	3.9	0.8	4	0.7	3	0.6	1.9	0.5	1.7	ns
t _{en}	ŌĒ	A or B	8.4	1.5	9.2	1.4	7	1	4.3	0.7	3.7	ns
t _{dis}	ŌĒ	A or B	8.4	2.3	9.3	2.2	7	1.1	4	1.2	3.9	ns

Operating Characteristics

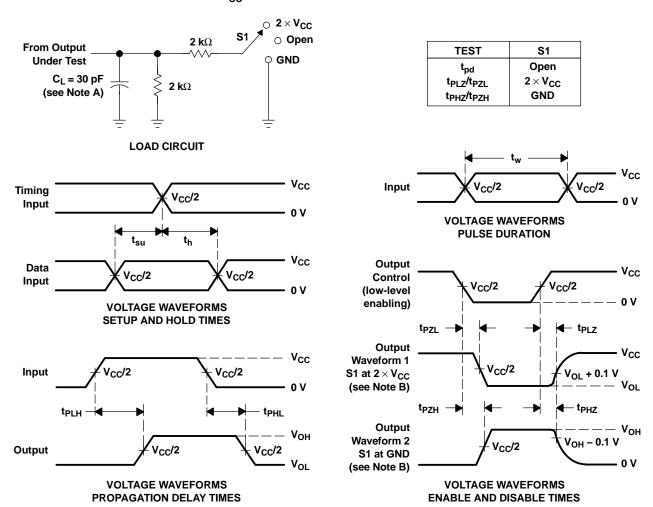
 $T_A = 25^{\circ}C$

	PARAMETER		TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	UNIT	
0	Power dissipation Outputs		C 0 f 10 MHz	35	38	44	"C	
C_{pd}	capacitance	Outputs disabled	$C_L = 0$, $f = 10 \text{ MHz}$	6	6	7	pF	

Typical values are measured at T_A = 25°C. For I/O ports, the parameter I_{OZ} includes the input leakage current.



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.2 \text{ V}$ AND 1.5 V \pm 0.1 V

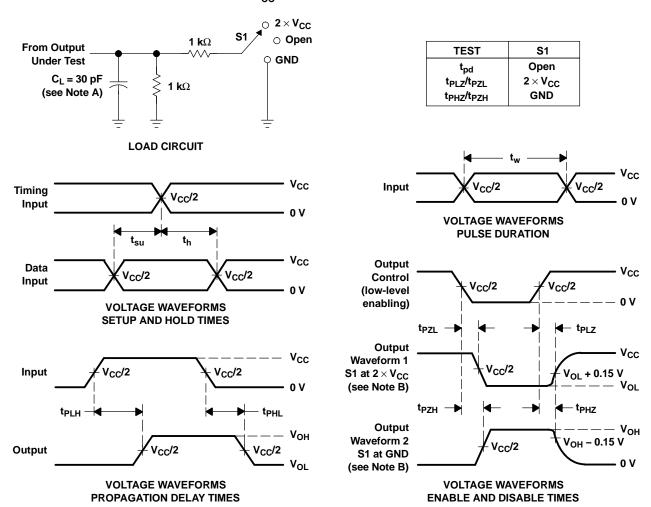


- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \ \Omega$, $t_f \leq 2 \ ns$, $t_f \leq 2 \ ns$.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 2. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$

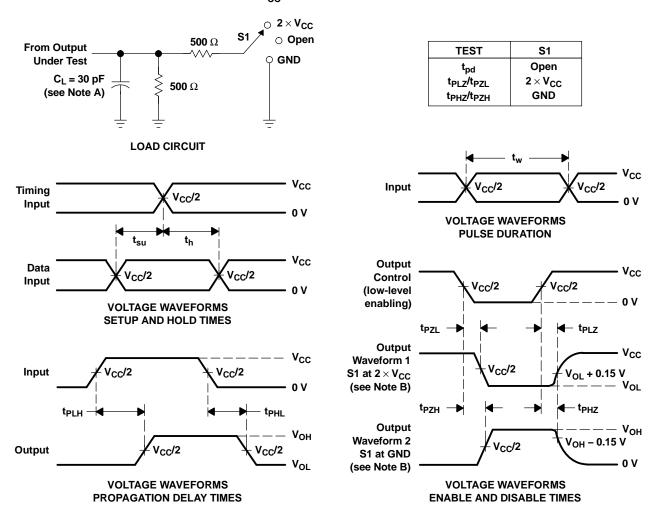


- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r \leq 2$ ns, $t_f \leq 2$ ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 3. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



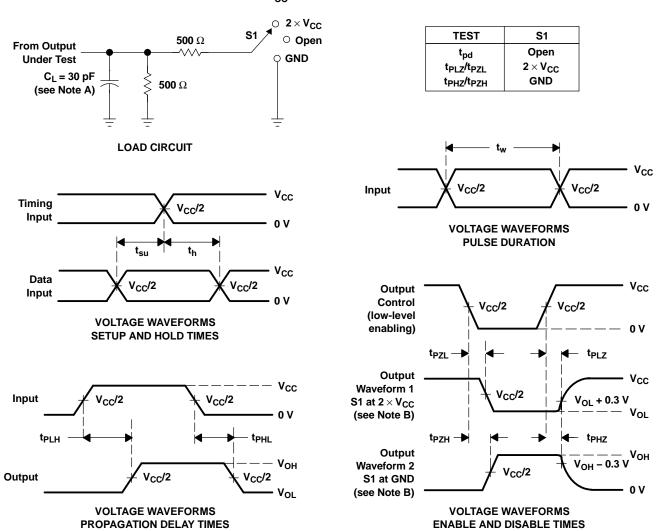
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r \leq 2$ ns, $t_f \leq 2$ ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.

Figure 4. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$



NOTES: A. C₁ includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2$ ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.

Figure 5. Load Circuit and Voltage Waveforms





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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74AVC16245DGGRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AVC16245DGVRE4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AVC16245DGVRG4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AVC16245DGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AVC16245DGVR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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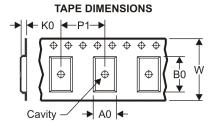
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PACKAGE MATERIALS INFORMATION

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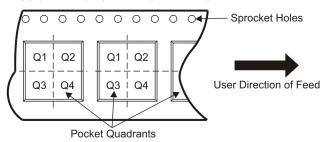
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVC16245DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.8	1.8	12.0	24.0	Q1
SN74AVC16245DGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVC16245DGGR	TSSOP	DGG	48	2000	346.0	346.0	41.0
SN74AVC16245DGVR	TVSOP	DGV	48	2000	346.0	346.0	33.0

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

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